

# The 2-Silaketenyldene (CSiO) Radical: Electronic Structure of the $\tilde{X}^3\Sigma^-$ and $\tilde{A}^3\Pi$ States<sup>†</sup>

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A theoretical study, using ab initio electronic structure theory, of the ground ( $\tilde{X}^3\Sigma^-$ ) and first excited triplet ( $\tilde{A}^3\Pi$ ) electronic states of the 2-silaketenyldene (CSiO) radical has been reported. The  $\tilde{A}^3\Pi$  state is subject to a Renner–Teller interaction and possesses two distinct real vibrational frequencies along the bending coordinate. To avoid variational collapse to a lower-lying state, the  $^3A''$  component of the  $\tilde{A}^3\Pi$  state was investigated using the equation of motion (EOM) CCSD technique. With the TZ3P(2f) EOM-CCSD method, the Renner parameter ( $\epsilon$ ) and bending harmonic vibrational frequency ( $\omega_2$ ) for the  $\tilde{A}^3\Pi$  state were determined to be  $\epsilon = -0.253$  and  $\omega_2 = 337 \text{ cm}^{-1}$ . At the highest level of theory, cc-pVQZ CCSD(T), the classical  $\tilde{X}$ – $\tilde{A}$  splitting of CSiO was predicted to be 29.8 kcal/mol (1.29 eV, 10 400  $\text{cm}^{-1}$ ), and the quantum mechanical energy separation to be 31.1 kcal/mol (1.35 eV, 10 900  $\text{cm}^{-1}$ ). The ground state of CSiO lies 65.4 kcal/mol above the ground state of SiCO. The bond energy for C–SiO was determined to be  $D_e = 32.6$  ( $D_0 = 31.4$ ) kcal/mol, indicating considerable stability for the ground state of CSiO against the dissociation reaction CSiO ( $\tilde{X}^3\Sigma^-$ )  $\rightarrow$  C ( $^3P$ ) + SiO ( $\tilde{X}^1\Sigma^+$ ). The most remarkable prediction from the present research is that the C–Si distance in the  $\tilde{A}^3\Pi$  excited state is nearly 0.2 Å less than that in the  $\tilde{X}^3\Sigma^-$  ground state. In fact, this distance (1.662 Å) is one of the shortest known Si–C bond distances with a formal bond order of  $5/2$ .

## I. Introduction

The ketenyldene radical (CCO) is known to be an important reactive intermediate involved in many chemical reactions in the gas phase.<sup>1</sup> This molecule has also been detected in the cold, dark interstellar molecular cloud TMC-1 by microwave spectroscopy.<sup>2</sup> The first spectroscopic study of the free radical CCO using the matrix-isolated infrared (IR) technique was performed by Jacox et al. in 1965.<sup>3</sup> They detected the three vibrational fundamentals of CCO in an argon matrix at 381, 1074, and 1978  $\text{cm}^{-1}$ . The absorption spectrum in the region 5000–6500 Å was observed by Devillers during the flash photolysis of carbon suboxide and was tentatively attributed to the CCO molecule.<sup>4</sup> These observations were extended to 9000 Å by Devillers and Ramsay.<sup>5</sup> The strong band near 8580 Å (11 650  $\text{cm}^{-1}$ ) was assigned as the 000–000 band of the  $\tilde{A}^3\Pi \leftarrow \tilde{X}^3\Sigma^-$  transition.<sup>5</sup> In 1977, Lembke et al. reported electron spin resonance (ESR) and optical spectra of the SiCO, SiN<sub>2</sub>, and Si(CO)<sub>2</sub> molecules.<sup>6</sup> From the ultraviolet absorption spectrum in an argon matrix at 4 K, they determined the  $\tilde{X}$ – $\tilde{A}$  splitting of SiCO, an isovalent isomer of CCO, to be 24 056  $\text{cm}^{-1}$ .<sup>6</sup> For other experimental studies on the CCO and SiCO radicals, readers should refer to the superb compilation by Jacox.<sup>7</sup>

The ground and first excited triplet electronic states of the isovalent species, CCO and SiCO, are experimentally<sup>1–7</sup> and theoretically<sup>8–17</sup> determined to be  $\tilde{X}^3\Sigma^-$  and  $\tilde{A}^3\Pi$  states, respectively, and they both present linear structures. The  $\tilde{A}^3\Pi$  states of CCO and SiCO are subjected to Renner–Teller interactions<sup>18–25</sup> and have two distinct vibrational frequencies along the bending coordinates. In two recent papers we have reported systematic studies for the ground and first excited triplet states of CCO<sup>15</sup> and SiCO<sup>17</sup> in their linear forms. For these two

ketenylidene radicals, it was demonstrated that the theoretical relative energies of the  $\tilde{X}$  and  $\tilde{A}$  states are converging in the direction of the experimental values in terms of basis set expansion and correlation level. At the highest level of theory employed, cc-pVQZ CCSD(T), the theoretically predicted  $\tilde{X}$ – $\tilde{A}$  splittings for the CCO and SiCO molecules agreed with the experimental values within a chemical accuracy of  $\pm 1$  kcal/mol. The present study for the CSiO molecule is a logical extension of our previous studies. To the best of our knowledge there are no experimental or theoretical investigations on the CSiO molecule. The two lowest-lying triplet states of CSiO will be investigated employing the self-consistent-field (SCF), configuration interaction with single and double excitations (CISD), coupled-cluster with single and double excitations (CCSD), and CCSD with perturbative triple excitations [CCSD(T)] methods with a wide range of basis sets. For the first excited triplet state ( $\tilde{A}^3\Pi$ ), the equation-of-motion (EOM) CCSD technique is also utilized to overcome possible variational collapse to a lower-lying state. The results for the CSiO molecule will be compared with those for the CCO and SiCO species.

## II. Electronic Structure Considerations

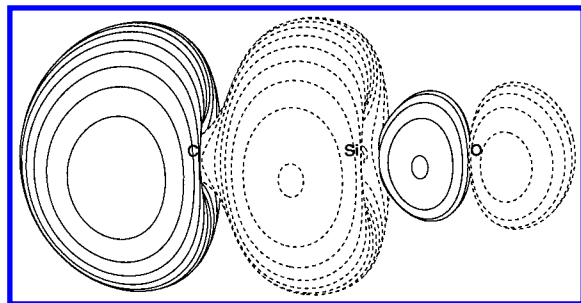
The electronic ground state of the linear CSiO radical has the electronic configuration

$$[\text{core}](6\sigma)^2(7\sigma)^2(8\sigma)^2(2\pi)^4(9\sigma)^2(3\pi_i)(3\pi_o) \quad \tilde{X}^3\Sigma^- \quad (1)$$

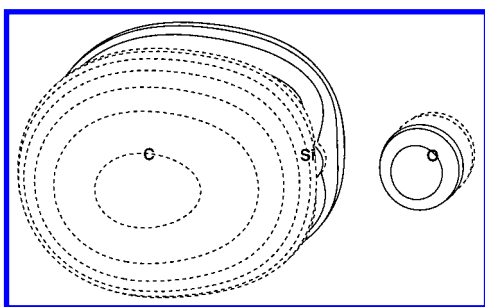
where [core] denotes the seven core (for Si, 1s-, 2s-, and 2p-like and for C and O, 1s-like) orbitals and  $\pi_i$  and  $\pi_o$  stand for in-plane and out-of-plane  $\pi$  orbitals, respectively. The 6 $\sigma$  and 7 $\sigma$  molecular orbitals (MOs) mainly represent the Si–O and C–Si  $\sigma$  bonds, whereas the 8 $\sigma$  and 9 $\sigma$  MOs are the lone-pair orbitals on the O and C atoms. The 2 $\pi$  and 3 $\pi$  MOs are attributed to the Si–O and C–Si  $\pi$  bonds, respectively. The 9 $\sigma$  and 3 $\pi$  MOs for the ground state of CSiO are depicted in

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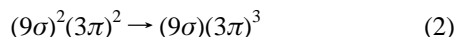


**Figure 1.**  $9\sigma$  molecular orbital for the  $\tilde{X}^3\Sigma^-$  state of CSiO from the TZ2P(f) SCF method.

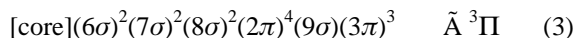


**Figure 2.**  $3\pi\sigma$  molecular orbital for the  $\tilde{X}^3\Sigma^-$  state of CSiO from the TZ2P(f) SCF method.

Figures 1 and 2, respectively. Upon bending, the molecular symmetry for the  $^3\Sigma^-$  ground state of CSiO reduces to a  $^3A''$  state, producing a real degenerate bending vibrational frequency. The first excited triplet state of CSiO is a single-electron excitation



to the electronic configuration



Upon the bending motion, the  $\tilde{A}^3\Pi$  state splits into  $^3A'$  and  $^3A''$  states. Thus, this  $\tilde{A}^3\Pi$  state presents the two distinct real vibrational frequencies along the bending coordinates. In other words, the  $\tilde{A}^3\Pi$  state of CSiO is subjected to Renner–Teller interaction,<sup>18–25</sup> and it is a type A Renner–Teller molecule, as classified by Lee et al., for linear triatomic molecules.<sup>24</sup>

It may be appropriate to discuss the molecular orbital Hessian<sup>26</sup> of the reference self-consistent-field wave functions in this section. At the linear configuration, the MO Hessian for the  $\tilde{X}^3\Sigma^-$  state of CSiO shows all positive eigenvalues, as expected. Thus, the SCF wave function for the  $\tilde{X}^3\Sigma^-$  state of CSiO is *stable*. The  $\tilde{A}^3\Pi$  state of CSiO has one zero and one negative eigenvalues of the MO Hessian. The eigenvector of the negative eigenvalue is associated with the  $9\sigma-3\pi$  MO rotation. Thus, the SCF wave function for the  $\tilde{A}^3\Pi$  state of CSiO is *unstable*, and a lower-lying state at the  $\tilde{A}^3\Pi$  equilibrium geometry exists. The magnitudes for the eigenvalues of the MO Hessian may also provide useful information for the stability of the SCF reference wave function.<sup>26–28</sup>

During the two stretching vibrational motions, the spatial symmetries for the  $\tilde{X}^3\Sigma^-$  and  $\tilde{A}^3\Pi$  states of CSiO remain the same. Consequently, these two stretching vibrational frequencies of the two triplet states can be determined without the variational collapse of the reference (SCF) wave functions. The bending vibrational frequencies of the  $\tilde{X}^3\Sigma^-$  state and the  $^3A'$  component of the  $\tilde{A}^3\Pi$  state can be also obtained correctly because of the spatial orthogonality of the reference SCF wave functions. However, the  $^3A''$  component of the  $\tilde{A}^3\Pi$  state is the second

state of its symmetry. Because the typical one-configuration SCF wave function can not be used for the  $^3A''$  component of the  $\tilde{A}^3\Pi$  state, the EOM-CCSD technique was utilized, and the  $^3A''$  component was obtained as the second root ( $2^3A''$ ) of the reference bent ground state ( $1^3A'$ ).

### III. Renner–Teller Interaction

As mentioned above, the  $\tilde{A}^3\Pi$  state of CSiO is subjected to Renner–Teller interaction<sup>18–25</sup> and presents two distinct bending vibrational frequencies. Following the discussion by Herzberg,<sup>21</sup> the Renner parameter ( $\epsilon$ ), which is a measure of the strength of the vibronic interaction, can be described in the following manner. The average potential ( $V^0$ ) of the “upper” ( $V^+$ ) and “lower” ( $V^-$ ) bending modes can be given, neglecting the anharmonic terms, as

$$V^0 = \frac{V^+ + V^-}{2} = ar^2 \quad (4)$$

and the splitting into  $V^+$  and  $V^-$  produced by the vibronic interaction can be represented by a similar equation

$$V = V^+ - V^- = \alpha r^2 \quad (5)$$

where  $r$  is the bending coordinate and  $a$  and  $\alpha$  are the force constants. The terms upper and lower are arbitrary in this section and are used to distinguish the two distinct bending motions. The Renner parameter ( $\epsilon$ ) is defined by

$$\epsilon = \frac{V^+ - V^-}{V^+ + V^-} = \frac{\alpha}{2a} \quad (6)$$

It can be shown that eq 6 is equivalent to

$$\epsilon = \frac{f^+ - f^-}{f^+ + f^-} = \frac{(\omega^+)^2 - (\omega^-)^2}{(\omega^+)^2 + (\omega^-)^2} \quad (7)$$

where  $f^+$  and  $f^-$  and  $\omega^+$  and  $\omega^-$  are the force constants and harmonic frequencies associated with the upper and lower bending potentials, respectively. Denoting  $\mu$  to be the kinetic energy contribution to the bending motion, the harmonic bending frequency ( $\omega_2$ ) can be determined using the equation

$$\omega_2 = \frac{1}{2\pi c} \sqrt{\frac{a}{\mu}} = \frac{1}{2\pi c} \sqrt{\frac{f^+ + f^-}{2\mu}} \quad (8)$$

which can be rewritten as

$$\omega_2 = \sqrt{\frac{1}{2}[(\omega^+)^2 + (\omega^-)^2]} \quad (9)$$

Finally, the upper and lower bending frequencies are related to the  $\omega_2$  frequency using the Renner parameter by

$$\omega^\pm = \omega_2 \sqrt{1 \pm \epsilon} \quad (10)$$

Utilizing eqs 4–10, the experimentally observable values,  $\epsilon$  and  $\omega_2$ , can be compared with the corresponding theoretical values that can be evaluated completely independently.

### IV. Theoretical Procedures

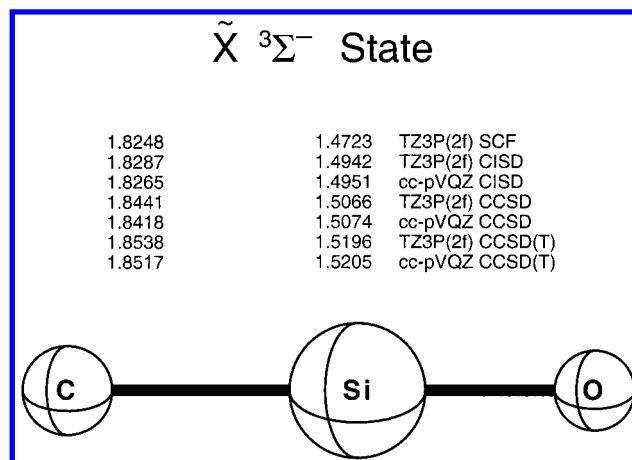
Eight basis sets were employed in order to determine structures and physical properties. The basis sets of triple- $\zeta$  (TZ) quality for C and O are obtained from Dunning’s triple- $\zeta$

**TABLE 1: Optimized Structures for the  $\tilde{X}^3\Sigma^-$  and  $\tilde{A}^3\Pi$  States of the CSiO Molecule<sup>a</sup>**

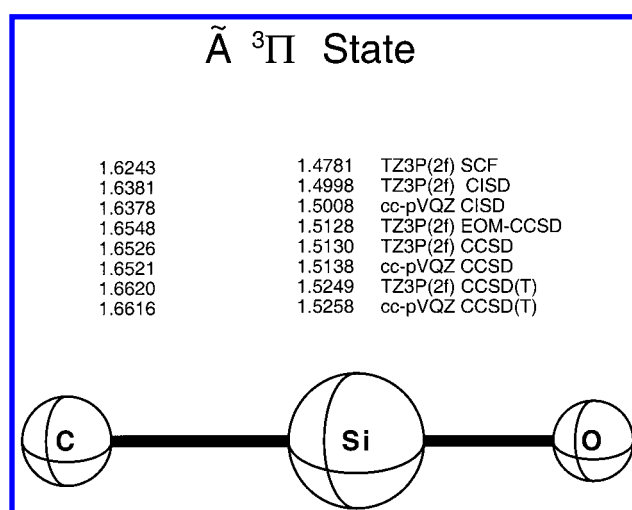
| electronic state<br>level of theory | $\tilde{X}^3\Sigma^-$ state |                   | $\tilde{A}^3\Pi$ state |                   |
|-------------------------------------|-----------------------------|-------------------|------------------------|-------------------|
|                                     | $r_e(\text{CSi})$           | $r_e(\text{SiO})$ | $r_e(\text{CSi})$      | $r_e(\text{SiO})$ |
| TZ2P SCF                            | 1.8291                      | 1.4760            | 1.6266                 | 1.4823            |
| TZ2P+diff SCF                       | 1.8290                      | 1.4763            | 1.6269                 | 1.4825            |
| TZ3P SCF                            | 1.8270                      | 1.4738            | 1.6240                 | 1.4795            |
| TZ2P(f) SCF                         | 1.8273                      | 1.4756            | 1.6255                 | 1.4818            |
| TZ2P(f)+diff SCF                    | 1.8272                      | 1.4760            | 1.6257                 | 1.4822            |
| TZ3P(2f) SCF                        | 1.8248                      | 1.4723            | 1.6243                 | 1.4781            |
| TZ2P CISD                           | 1.8478                      | 1.5009            | 1.6453                 | 1.5076            |
| TZ2P+diff CISD                      | 1.8479                      | 1.5012            | 1.6458                 | 1.5078            |
| TZ3P CISD                           | 1.8404                      | 1.4981            | 1.6414                 | 1.5040            |
| TZ2P(f) CISD                        | 1.8340                      | 1.4982            | 1.6401                 | 1.5046            |
| TZ2P(f)+diff CISD                   | 1.8342                      | 1.4987            | 1.6404                 | 1.5051            |
| TZ3P(2f) CISD                       | 1.8287                      | 1.4942            | 1.6381                 | 1.4998            |
| cc-pVTZ CISD                        | 1.8361                      | 1.5014            | 1.6446                 | 1.5076            |
| cc-pVQZ CISD                        | 1.8265                      | 1.4951            | 1.6378                 | 1.5008            |
| TZ2P EOM-CCSD <sup>b</sup>          | (1.8650)                    | (1.5138)          | 1.6634                 | 1.5211            |
| TZ2P+diff EOM-CCSD                  | (1.8653)                    | (1.5141)          | 1.6641                 | 1.5214            |
| TZ3P EOM-CCSD                       | (1.8567)                    | (1.5107)          | 1.6587                 | 1.5171            |
| TZ2P(f) EOM-CCSD                    | (1.8493)                    | (1.5110)          | 1.6570                 | 1.5180            |
| TZ2P(f)+diff EOM-CCSD               | (1.8498)                    | (1.5116)          | 1.6575                 | 1.5185            |
| TZ3P(2f) EOM-CCSD                   | (1.8441)                    | (1.5066)          | 1.6548                 | 1.5128            |
| cc-pVTZ EOM-CCSD                    | (1.8511)                    | (1.5140)          | 1.6616                 | 1.5208            |
| TZ2P CCSD                           | 1.8650                      | 1.5138            | 1.6605                 | 1.5214            |
| TZ2P+diff CCSD                      | 1.8653                      | 1.5141            | 1.6612                 | 1.5217            |
| TZ3P CCSD                           | 1.8567                      | 1.5107            | 1.6563                 | 1.5174            |
| TZ2P(f) CCSD                        | 1.8493                      | 1.5110            | 1.6545                 | 1.5182            |
| TZ2P(f)+diff CCSD                   | 1.8498                      | 1.5116            | 1.6550                 | 1.5188            |
| TZ3P(2f) CCSD                       | 1.8441                      | 1.5066            | 1.6526                 | 1.5130            |
| cc-pVTZ CCSD                        | 1.8511                      | 1.5140            | 1.6591                 | 1.5210            |
| cc-pVQZ CCSD                        | 1.8418                      | 1.5074            | 1.6521                 | 1.5138            |
| TZ2P CCSD(T)                        | 1.8731                      | 1.5270            | 1.6702                 | 1.5335            |
| TZ2P+diff CCSD(T)                   | 1.8736                      | 1.5274            | 1.6709                 | 1.5339            |
| TZ3P CCSD(T)                        | 1.8655                      | 1.5239            | 1.6658                 | 1.5295            |
| TZ2P(f) CCSD(T)                     | 1.8582                      | 1.5243            | 1.6639                 | 1.5303            |
| TZ2P(f)+diff CCSD(T)                | 1.8589                      | 1.5248            | 1.6644                 | 1.5309            |
| TZ3P(2f) CCSD(T)                    | 1.8538                      | 1.5196            | 1.6620                 | 1.5249            |
| cc-pVTZ CCSD(T)                     | 1.8602                      | 1.5270            | 1.6687                 | 1.5329            |
| cc-pVQZ CCSD(T)                     | 1.8517                      | 1.5205            | 1.6616                 | 1.5258            |

<sup>a</sup> Bond lengths are in Å. <sup>b</sup> EOM-CCSD is equivalent to CCSD for the ground state. Bond lengths labeled EOM-CCSD were calculated with the ACES II package.<sup>49</sup>

contraction<sup>29</sup> of Huzinaga's primitive Gaussian set<sup>30</sup> and are designated (10s6p/5s3p). The TZ basis set for Si is derived from McLean and Chandler's contraction<sup>31</sup> of Huzinaga's primitive Gaussian set<sup>32</sup> and is designated (12s9p/6s5p). The orbital exponents of the polarization functions are  $\alpha_d(\text{C}) = 1.50$  and  $0.375$ ,  $\alpha_d(\text{O}) = 1.70$  and  $0.425$ , and  $\alpha_d(\text{Si}) = 1.00$  and  $0.25$  for double polarization (TZ2P); and  $\alpha_d(\text{C}) = 3.00$ ,  $0.75$ , and  $0.1875$ ,  $\alpha_d(\text{O}) = 3.40$ ,  $0.85$ , and  $0.2125$ , and  $\alpha_d(\text{Si}) = 2.00$ ,  $0.50$ , and  $0.125$  for triple polarization (TZ3P). The orbital exponents of the higher angular momentum functions are  $\alpha_f(\text{C}) = 0.80$ ,  $\alpha_f(\text{O}) = 1.40$ , and  $\alpha_f(\text{Si}) = 0.32$  for one set of higher angular momentum functions [TZ2P(f)]; and  $\alpha_f(\text{C}) = 1.60$  and  $0.40$ ,  $\alpha_f(\text{O}) = 2.80$  and  $0.70$ , and  $\alpha_f(\text{Si}) = 0.64$  and  $0.16$  for two sets of higher angular momentum functions [TZ3P(2f)]. The orbital exponents of the diffuse functions are  $\alpha_p(\text{C}) = 0.03389$  and  $\alpha_s(\text{C}) = 0.04812$ ,  $\alpha_p(\text{O}) = 0.05840$  and  $\alpha_s(\text{O}) = 0.08993$ , and  $\alpha_p(\text{Si}) = 0.02354$  and  $\alpha_s(\text{Si}) = 0.02567$  for one set of diffuse functions [TZ2P+diff and TZ2P(f)+diff]. Pure angular momentum d and f functions were used throughout. The largest TZ-plus basis set, TZ3P(2f), comprises 136 contracted Gaussian functions with a contraction scheme of C and O (10s6p3d2f/5s3p3d2f), and Si (12s9p3d2f/6s5p3d2f). Finally, the two correlation-consistent basis sets, cc-pVTZ and cc-pVQZ, de-



**Figure 3.** Predicted geometries for the  $\tilde{X}^3\Sigma^-$  state of CSiO at the four levels of sophistication with the TZ3P(2f) and cc-pVQZ basis sets. Bond lengths are in Å.



**Figure 4.** Predicted geometries for the  $\tilde{A}^3\Pi$  state of CSiO at the five levels of sophistication with the TZ3P(2f) and cc-pVQZ basis sets. Bond lengths are in Å.

veloped by Dunning and Woon<sup>33,34</sup> have also been used. The cc-pVQZ basis set consists of 169 contracted Gaussian functions with a contraction scheme of C and O (12s6p3d2f1g/5s4p3d2f1g) and Si (16s11p3d2f1g/6s5p3d2f1g).

The zeroth-order descriptions for the  $\tilde{X}^3\Sigma^-$  and  $\tilde{A}^3\Pi$  states of CSiO were obtained using one-configuration SCF (restricted Hartree–Fock) wave functions. Correlation effects were included using the configuration interaction with single and double excitations (CISD), coupled-cluster with single and double excitations (CCSD),<sup>35,36</sup> and CCSD with perturbative triple excitations [CCSD(T)]<sup>37,38</sup> levels of theory. The  $\tilde{A}^3\Pi$  state of CSiO was also investigated employing the equation-of-motion (EOM) CCSD technique.<sup>39–42</sup> In correlated procedures with the TZ-plus basis sets, the seven core (for Si, 1s-, 2s-, and 2p-like and for C and O, 1s-like) orbitals were frozen, and the three highest-lying virtual (for Si, C, and O, 1s\*-like) orbitals were deleted. The correlated wave functions with the two correlation-consistent basis sets were constructed by freezing the seven core orbitals only. With the cc-pVQZ basis set, the numbers of configuration state functions (CSFs) in the Hartree–Fock interacting spaces<sup>43,44</sup> in the CISD procedures are 190 782 for the  $\tilde{X}^3\Sigma^-$  state in  $C_{2v}$  symmetry and 375 642 in  $C_s$  symmetry, and 190 586 for the  $\tilde{A}^3\Pi$  state in  $C_{2v}$  symmetry and 375 151 in  $C_s$  symmetry.

The structures of the two stationary points were optimized

**TABLE 2: Theoretical Predictions of the Total Energy, Dipole Moment, Harmonic Vibrational Frequencies, Infrared (IR) Intensities, and Zero-Point Vibrational Energy (ZPVE) for the  $\tilde{X}^3\Sigma^-$  State of the CSiO Molecule**

| level of theory      | energy       | $\mu_e$ | $\omega_1(\sigma)$<br>SiO stretch | $\omega_2(\pi)$<br>bend | $\omega_3(\sigma)$<br>CSi stretch | ZPVE |
|----------------------|--------------|---------|-----------------------------------|-------------------------|-----------------------------------|------|
| TZ2P SCF             | -401.535 164 | 0.588   | 1416 (101.4)                      | 181 (158.4)             | 624 (15.7)                        | 3.43 |
| TZ2P+diff SCF        | -401.536 097 | 0.647   | 1415 (105.1)                      | 179 (159.0)             | 626 (16.4)                        | 3.43 |
| TZ3P SCF             | -401.537 464 | 0.613   | 1424 (100.1)                      | 181 (156.3)             | 628 (16.7)                        | 3.45 |
| TZ2P(f) SCF          | -401.539 443 | 0.572   | 1418 (101.3)                      | 175 (166.8)             | 630 (14.8)                        | 3.43 |
| TZ2P(f)+diff SCF     | -401.540 262 | 0.638   | 1416 (106.0)                      | 169 (164.2)             | 631 (15.6)                        | 3.41 |
| TZ3P(2f) SCF         | -401.544 044 | 0.614   | 1429 (100.2)                      | 180 (158.7)             | 638 (16.2)                        | 3.47 |
| TZ2P CISD            | -401.907 303 | 0.700   | 1325 (59.0)                       | 124 (106.7)             | 649 (11.6)                        | 3.18 |
| TZ2P+diff CISD       | -401.908 815 | 0.769   | 1324 (62.1)                       | 117 (106.9)             | 649 (12.5)                        | 3.15 |
| TZ3P CISD            | -401.914 388 | 0.713   | 1339 (57.8)                       | 125 (106.8)             | 661 (13.2)                        | 3.22 |
| TZ2P(f) CISD         | -401.941 625 | 0.646   | 1337 (60.6)                       | 124 (118.6)             | 678 (10.8)                        | 3.24 |
| TZ2P(f)+diff CISD    | -401.942 983 | 0.721   | 1336 (64.0)                       | 115 (116.5)             | 678 (11.8)                        | 3.21 |
| TZ3P(2f) CISD        | -401.956 798 | 0.673   | 1354 (60.2)                       | 140 (115.2)             | 690 (12.4)                        | 3.32 |
| cc-pVTZ CISD         | -401.946 499 | 0.577   | 1348 (54.5)                       | 141 (109.9)             | 682 (11.0)                        | 3.30 |
| cc-pVQZ CISD         | -401.984 627 | -       | 1357 (-)                          | 140 (-)                 | 696 (-)                           | 3.34 |
| TZ2P CCSD            | -401.954 087 |         | 1270                              | 64                      | 622                               | 2.89 |
| TZ2P+diff CCSD       | -401.955 754 |         | 1269                              | 46                      | 622                               | 2.83 |
| TZ3P CCSD            | -401.961 724 |         | 1285                              | 66                      | 634                               | 2.93 |
| TZ2P(f) CCSD         | -401.992 060 |         | 1283                              | 61                      | 653                               | 2.94 |
| TZ2P(f)+diff CCSD    | -401.993 572 |         | 1281                              | 41                      | 652                               | 2.88 |
| TZ3P(2f) CCSD        | -402.008 372 |         | 1301                              | 89                      | 664                               | 3.06 |
| cc-pVTZ CCSD         | -401.997 573 |         | 1294                              | 92                      | 657                               | 3.05 |
| cc-pVQZ CCSD         | -402.038 281 |         | 1303                              | 90                      | 671                               | 3.08 |
| TZ2P CCSD(T)         | -401.978 076 |         | 1214                              | 31i                     | 627                               | 2.63 |
| TZ2P+diff CCSD(T)    | -401.979 858 |         | 1213                              | 56i                     | 626                               | 2.63 |
| TZ3P CCSD(T)         | -401.986 406 |         | 1229                              | 39i                     | 636                               | 2.67 |
| TZ2P(f) CCSD(T)      | -402.018 311 |         | 1226                              | 79                      | 653                               | 2.91 |
| TZ2P(f)+diff CCSD(T) | -402.019 920 |         | 1225                              | 126                     | 651                               | 3.04 |
| TZ3P(2f) CCSD(T)     | -402.035 826 |         | 1245                              | 129                     | 661                               | 3.09 |
| cc-pVTZ CCSD(T)      | -402.024 468 |         | 1238                              | 61                      | 656                               | 2.88 |
| cc-pVQZ CCSD(T)      | -402.067 432 |         | 1247                              | 60                      | 667                               | 2.91 |

<sup>a</sup> Total energies are in hartree, dipole moments are in debye, harmonic vibrational frequencies are in  $\text{cm}^{-1}$ , infrared (IR) intensities (in parentheses) are in  $\text{km mol}^{-1}$ , and zero-point vibrational energies (ZPVE) are in kcal/mol. IR intensities of the  $\omega_2$  mode were doubled.

using analytic derivative methods.<sup>45–47</sup> Harmonic vibrational frequencies at the SCF level were evaluated analytically, at the CISD level of theory by finite differences of analytic gradients, and at the CCSD, EOM-CCSD, and CCSD(T) levels of theory by five-point numerical differentiation of total energies. All computations were carried out using the PSI 2.0.8 program package,<sup>48</sup> except for EOM-CCSD wave functions, which were carried out using the ACES II package,<sup>49</sup> on IBM RS/6000 workstations.

## V. Results and Discussion

The bond lengths for the ground ( $\tilde{X}^3\Sigma^-$ ) and first excited triplet ( $\tilde{A}^3\Pi$ ) states of CSiO are provided in Table 1. Figures 3 and 4 depict the optimized geometries at the four (five) levels of sophistication using the TZ3P(2f) and cc-pVQZ basis sets. The total energies and physical properties for the  $\tilde{X}^3\Sigma^-$  and  $\tilde{A}^3\Pi$  states of CSiO radical are presented in Tables 2 and 3, respectively.

**A. Geometries.** The optimized geometries for the  $\tilde{X}^3\Sigma^-$  state and  $\tilde{A}^3\Pi$  state of CSiO are presented in Table 1 and in Figures 3 and 4, respectively. The ground and first excited triplet states of CSiO have linear equilibrium structures, as was the case for  $\text{CCO}^{15}$  and  $\text{SiCO}^{17}$ . The two bonds of the two states are generally elongated with improved treatments of correlation effects and are shortened with increased basis set size. The C–Si bond of the first excited triplet state is predicted to be significantly shorter (about 0.2 Å) than that of the ground state, whereas the Si–O bond is predicted to be slightly longer (about 0.005–0.008 Å). The 9s MO in eq 1 (in Figure 1) is a lone-pair (nonbonding) orbital on the C atom, and the  $3\pi$  MO (in

Figure 2) has strong C–Si  $\pi$  bonding and weak Si–O anti- $\pi$  bonding character. Consequently, a single-electron excitation in eq 2 results in a distinct contraction of the C–Si bond and a marginal elongation of the Si–O bond. With the cc-pVQZ CCSD(T) method the equilibrium bond distance of the diatomic SiO ( $\tilde{X}^1\Sigma^+$ ) is  $r_e = 1.5201$  Å, while the experimental value is  $r_e = 1.5097$  Å.<sup>50</sup> It is seen that the SiO bond distance for the  $\tilde{X}^3\Sigma^-$  state of CSiO is close to that of the diatomic SiO. The internuclear separations of the diatomic SiC radical were experimentally found to be  $r_0 = 1.72187$  Å ( $\tilde{X}^3\Pi$ ) and  $r_0 = 1.81356$  Å ( $\tilde{A}^3\Sigma^-$ ).<sup>51</sup> The  $r_e$  (CSi) for the  $\tilde{X}^3\Sigma^-$  state of CSiO is close to the  $r_0$  value of the  $\tilde{A}^3\Sigma^-$  state of the diatomic SiC. For the  $\tilde{A}^3\Pi$  state, the EOM-CCSD method predicts geometries similar to those from the CCSD method rather than those from the CISD method. The sums of the bond lengths for the two states are 3.3722 (1.8517 + 1.5205) Å and 3.1874 (1.6616 + 1.5258) Å, respectively, with the cc-pVQZ CCSD(T) method. It is seen that the  $\tilde{A}^3\Pi$  state presents a contracted structure of about 0.185 (3.372–3.187) Å (–5.5%) compared to that of the  $\tilde{X}^3\Sigma^-$  state. Similar geometrical trends have been observed for the  $\tilde{X}^3\Sigma^-$  and  $\tilde{A}^3\Pi$  states of the  $\text{CCO}^{15}$  and  $\text{SiCO}^{17}$  systems.

Our predicted C–Si bond distance of 1.662 Å for the  $\tilde{A}^3\Pi$  state is one of the shortest known Si–C bond distance. Only a few Si=C double-bond distances are known experimentally, including 1.702 Å for  $\text{Me}_2\text{Si}=\text{C}(\text{SiMe}_3)(\text{SiMe-t-Bu})$ ,<sup>52</sup> 1.692 Å for  $(\text{CH}_3)_2\text{Si}=\text{CH}_2$ ,<sup>53</sup> and 1.704 Å for the parent  $\text{H}_2\text{Si}=\text{CH}_2$ .<sup>54</sup> By this criteria, the C–Si bond in the  $\tilde{A}^3\Pi$  state of CSiO would appear to be a strong double bond. This is consistent with an Si–C bond of formal order 2.5, due to two electrons in the  $7\sigma$  bonding orbital and three electrons in the  $3\pi$  bonding orbital.

**TABLE 3: Theoretical Predictions of the Total Energy, Dipole Moment, Harmonic Vibrational Frequencies, and Infrared Intensities for the  $\tilde{A}^3\Pi$  State of the CSiO Molecule<sup>a</sup>**

| level of theory       | energy       | $\mu_e$ | $\omega_1(\sigma)$<br>SiO stretch | $\omega_2(\pi_i, {}^3A'')$<br>bend | $\omega_2(\pi_o, {}^3A')$<br>bend | $\omega_3(\sigma)$<br>CSi stretch |
|-----------------------|--------------|---------|-----------------------------------|------------------------------------|-----------------------------------|-----------------------------------|
| TZ2P SCF              | -401.495 785 | 1.988   | 1498 (213.7)                      | 484 (9.1)                          | 330 (87.8)                        | 1071 (0.0)                        |
| TZ2P+diff SCF         | -401.496 477 | 2.047   | 1496 (217.0)                      | 482 (8.4)                          | 329 (87.3)                        | 1070 (0.0)                        |
| TZ3P SCF              | -401.498 664 | 2.030   | 1508 (207.8)                      | 490 (9.7)                          | 324 (83.6)                        | 1075 (0.0)                        |
| TZ2P(f) SCF           | -401.501 583 | 1.955   | 1501 (213.8)                      | 500 (7.7)                          | 326 (92.2)                        | 1072 (0.0)                        |
| TZ2P(f)+diff SCF      | -401.502 209 | 2.020   | 1499 (219.2)                      | 495 (6.3)                          | 324 (90.4)                        | 1071 (0.0)                        |
| TZ3P(2f) SCF          | -401.506 699 | 1.990   | 1510 (209.4)                      | 508 (7.3)                          | 325 (84.5)                        | 1076 (0.0)                        |
| TZ2P CISD             | -401.860 379 | 1.752   | 1406 (129.5)                      |                                    | 292 (61.2)                        | 1000 (0.0)                        |
| TZ2P+diff CISD        | -401.861 644 | 1.818   | 1404 (133.3)                      |                                    | 290 (60.8)                        | 999 (0.0)                         |
| TZ3P CISD             | -401.868 523 | 1.787   | 1424 (127.4)                      |                                    | 289 (58.4)                        | 1010 (0.0)                        |
| TZ2P(f) CISD          | -401.897 879 | 1.732   | 1423 (133.3)                      |                                    | 292 (66.2)                        | 1012 (0.0)                        |
| TZ2P(f)+diff CISD     | -401.898 999 | 1.805   | 1421 (137.9)                      |                                    | 291 (64.7)                        | 1011 (0.0)                        |
| TZ3P(2f) CISD         | -401.913 847 | 1.765   | 1437 (134.0)                      |                                    | 296 (61.1)                        | 1020 (0.0)                        |
| cc-pVTZ CISD          | -401.901 040 | 1.671   | 1431 (121.4)                      |                                    | 297 (59.6)                        | 1014 (0.1)                        |
| cc-pVQZ CISD          | -401.941 520 | -       | 1440 (-)                          |                                    | 296 (-)                           | 1022 (-)                          |
| TZ2P EOM-CCSD         | -401.904 778 |         | 1342                              | 364                                | 286                               | 944                               |
| TZ2P+diff EOM-CCSD    | -401.906 197 |         | 1340                              | 357                                | 282                               | 942                               |
| TZ3P EOM-CCSD         | -401.913 466 |         | 1362                              | 362                                | 282                               | 956                               |
| TZ2P(f) EOM-CCSD      | -401.946 153 |         | 1361                              | 372                                | 288                               | 958                               |
| TZ2P(f)+diff EOM-CCSD | -401.947 416 |         | 1358                              | 367                                | 285                               | 957                               |
| TZ3P(2f) EOM-CCSD     | -401.963 204 |         | 1376                              | 377                                | 291                               | 967                               |
| cc-pVTZ EOM-CCSD      | -401.950 083 |         | 1370                              | 374                                | 291                               | 960                               |
| TZ2P CCSD             | -401.905 034 |         | 1345                              |                                    | 271                               | 950                               |
| TZ2P+diff CCSD        | -401.906 470 |         | 1343                              |                                    | 267                               | 948                               |
| TZ3P CCSD             | -401.913 786 |         | 1365                              |                                    | 267                               | 961                               |
| TZ2P(f) CCSD          | -401.946 285 |         | 1363                              |                                    | 271                               | 964                               |
| TZ2P(f)+diff CCSD     | -401.947 561 |         | 1361                              |                                    | 269                               | 962                               |
| TZ3P(2f) CCSD         | -401.963 427 |         | 1378                              |                                    | 276                               | 972                               |
| cc-pVTZ CCSD          | -401.950 221 |         | 1372                              |                                    | 276                               | 965                               |
| cc-pVQZ CCSD          | -401.993 223 |         | 1382                              |                                    | 276                               | 974                               |
| TZ2P CCSD(T)          | -401.926 824 |         | 1302                              |                                    | 254                               | 913                               |
| TZ2P+diff CCSD(T)     | -401.928 383 |         | 1300                              |                                    | 253                               | 912                               |
| TZ3P CCSD(T)          | -401.936 307 |         | 1316                              |                                    | 252                               | 920                               |
| TZ2P(f) CCSD(T)       | -401.970 148 |         | 1320                              |                                    | 256                               | 927                               |
| TZ2P(f)+diff CCSD(T)  | -401.971 529 |         | 1318                              |                                    | 254                               | 926                               |
| TZ3P(2f) CCSD(T)      | -401.988 514 |         | 1335                              |                                    | 262                               | 936                               |
| cc-pVTZ CCSD(T)       | -401.974 855 |         | 1329                              |                                    | 260                               | 929                               |
| cc-pVQZ CCSD(T)       | -402.020 001 |         | 1338                              |                                    | 261                               | 938                               |

<sup>a</sup> Total energies are in hartree, dipole moments are in debye, harmonic vibrational frequencies are in  $\text{cm}^{-1}$ , and infrared (IR) intensities (in parentheses) are in  $\text{km mol}^{-1}$ .

The only shorter Si–C bond distance determined experimentally is that very recently reported for the  $\tilde{A}^2\Sigma^+$  excited state of SiCH by Smith et al.<sup>55</sup> This group found an Si–C distance of 1.612 Å for the first excited electronic state of SiCH. Smith and co-workers describe the  $\tilde{A}^2\Sigma^+$  state of SiCH as incorporating a Si–C triple bond. This is consistent with our characterization of the  $\tilde{A}^3\Pi$  state of CSiO as a system of bond order  $5/2$ .

**B. Dipole Moments.** The dipole moment of the ground state,  $\mu_e(^+CSiO^-) = 0.67$  D with the TZ3P(2f) CISD method, is relatively small, whereas that of the first excited triplet state,  $\mu_e(^+CSiO^-) = 1.77$  D with the same method, is considerably larger. The signs indicate the direction of the dipole moments. The single-electron excitation in eq 2 appears to make the CSiO molecule more polar. This feature is also seen for the SiCO system: the dipole moment for the  $\tilde{A}^3\Pi$  of SiCO,  $\mu_e(^+SiCO^-) = 2.49$  D with TZ3P(2f) CISD method, is markedly greater than that for the  $\tilde{X}^3\Sigma^-$  state of SiCO,  $\mu_e(^+SiCO^-) = 0.29$  D with the same method. The theoretically predicted dipole moment of the diatomic SiO ( $\tilde{X}^1\Sigma^+$ ) is  $\mu_e(^+SiO^-) = 3.28$  D with the TZ3P(2f) CISD method, whereas the experimental value is  $\mu_e = 3.098$  D.<sup>50</sup> The dipole moments for the two low-lying states of CSiO are significantly smaller than the dipole moment of the diatomic SiO ( $\tilde{X}^1\Sigma^+$ ).

**C. Harmonic Vibrational Frequencies.** As seen in Table 2, the SiO stretching ( $\omega_1$ ) and CSi stretching ( $\omega_3$ ) frequencies

of the  $\tilde{X}^3\Sigma^-$  state generally decrease with improved treatment of correlation effects because of elongated bonds. This feature is consistent with Badger's rule that a shorter bond is associated with a higher vibrational frequency (or a larger stretching force constant).<sup>56,57</sup> The bending ( $\omega_2$ ) frequency generally diminishes with the level of sophistication. At the CCSD(T) level of theory, using the smaller basis sets (i.e., those without f functions), the bending frequency becomes imaginary. The ground state of CSiO is seen to be very floppy with respect to the bending motion.

For the  $\tilde{A}^3\Pi$  state, all three vibrational frequencies decrease with advanced treatments of correlation effects. These three harmonic vibrational frequencies are higher for the excited triplet state than those for the ground state, probably because of the contracted structure of the  $\tilde{A}^3\Pi$  state, as mentioned above. The EOM-CCSD technique provides harmonic vibrational frequencies that are reasonably consistent with those from the CCSD method. The in-plane bending frequency (in the  ${}^3A''$  state) is predicted to be larger in magnitude than the out-of-plane bending frequency (in the  ${}^3A'$  state). With the cc-pVQZ CCSD(T) method, the harmonic vibrational frequency of the diatomic SiO ( $\tilde{X}^1\Sigma^+$ ) is predicted to be  $1235 \text{ cm}^{-1}$ , whereas the experimental value is  $1241.6 \text{ cm}^{-1}$ .<sup>50</sup> The SiO stretching frequency ( $1247 \text{ cm}^{-1}$  with the same method) for the  $\tilde{X}^3\Sigma^-$  state of CSiO has a magnitude similar to that for the diatomic SiO; however, the

**TABLE 4: Predicted Renner Parameter ( $\epsilon$ ) and Harmonic Bending Vibrational Frequency ( $\omega_2$ )<sup>a</sup> for the  $\tilde{A}^3\Pi$  State of CSiO, Neglecting Anharmonicity**

| level of theory       | $\omega_2^-(^3A'')$ | $\omega_2^+(^3A')$ | $\epsilon$ | $\omega_2$ |
|-----------------------|---------------------|--------------------|------------|------------|
| TZ2P EOM-CCSD         | 364                 | 286                | -0.237     | 327        |
| TZ2P+diff EOM-CCSD    | 357                 | 282                | -0.232     | 322        |
| TZ3P EOM-CCSD         | 362                 | 282                | -0.245     | 324        |
| TZ2P(f) EOM-CCSD      | 372                 | 288                | -0.250     | 333        |
| TZ2P(f)+diff EOM-CCSD | 367                 | 285                | -0.248     | 329        |
| TZ3P(2f) EOM-CCSD     | 377                 | 291                | -0.253     | 337        |
| cc-pVTZ EOM-CCSD      | 374                 | 291                | -0.246     | 335        |

<sup>a</sup> Harmonic bending vibrational frequencies are in  $\text{cm}^{-1}$ .**TABLE 5: Excitation Energies<sup>a</sup> for the  $\tilde{A}^3\Pi$  States of CSiO**

| level of theory       | $\Delta E$          |
|-----------------------|---------------------|
| TZ2P SCF              | 24.71, 1.072, 8640  |
| TZ2P+diff SCF         | 24.86, 1.078, 8700  |
| TZ3P SCF              | 24.35, 1.056, 8520  |
| TZ2P(f) SCF           | 23.76, 1.030, 8310  |
| TZ2P(f)+diff SCF      | 23.88, 1.035, 8350  |
| TZ3P(2f) SCF          | 23.43, 1.016, 8200  |
| TZ2P CISD             | 29.45, 1.277, 10300 |
| TZ2P+diff CISD        | 29.60, 1.284, 10350 |
| TZ3P CISD             | 28.78, 1.248, 10070 |
| TZ2P(f) CISD          | 27.45, 1.190, 9600  |
| TZ2P(f)+diff CISD     | 27.60, 1.197, 9650  |
| TZ3P(2f) CISD         | 26.95, 1.169, 9430  |
| cc-pVTZ CISD          | 28.53, 1.237, 9980  |
| cc-pVQZ CISD          | 27.05, 1.173, 9460  |
| TZ2P EOM-CCSD         | 30.94, 1.342, 10820 |
| TZ2P+diff EOM-CCSD    | 31.10, 1.349, 10880 |
| TZ3P EOM-CCSD         | 30.28, 1.313, 10590 |
| TZ2P(f) EOM-CCSD      | 28.81, 1.249, 10080 |
| TZ2P(f)+diff EOM-CCSD | 28.96, 1.256, 10130 |
| TZ3P(2f) EOM-CCSD     | 28.34, 1.229, 9910  |
| cc-pVTZ EOM-CCSD      | 29.80, 1.292, 10420 |
| TZ2P CCSD             | 30.78, 1.335, 10770 |
| TZ2P+diff CCSD        | 30.93, 1.341, 10820 |
| TZ3P CCSD             | 30.08, 1.304, 10520 |
| TZ2P(f) CCSD          | 28.72, 1.246, 10050 |
| TZ2P(f)+diff CCSD     | 28.87, 1.252, 10100 |
| TZ3P(2f) CCSD         | 28.20, 1.223, 9860  |
| cc-pVTZ CCSD          | 29.71, 1.289, 10390 |
| cc-pVQZ CCSD          | 28.27, 1.226, 9890  |
| TZ2P CCSD(T)          | 32.16, 1.395, 11250 |
| TZ2P+diff CCSD(T)     | 32.30, 1.401, 11300 |
| TZ3P CCSD(T)          | 31.44, 1.363, 11000 |
| TZ2P(f) CCSD(T)       | 30.22, 1.311, 10570 |
| TZ2P(f)+diff CCSD(T)  | 30.37, 1.317, 10620 |
| TZ3P(2f) CCSD(T)      | 29.69, 1.287, 10380 |
| cc-pVTZ CCSD(T)       | 31.13, 1.350, 10890 |
| cc-pVQZ CCSD(T)       | 29.76, 1.291, 10410 |

<sup>a</sup> Energies are in  $\text{kcal mol}^{-1}$ , eV, and  $\text{cm}^{-1}$ .

SiO stretch of the  $\tilde{A}^3\Pi$  state has a higher (by  $96 \text{ cm}^{-1}$ ) frequency than that for diatomic SiO.

**D. Infrared (IR) Intensities.** The bending ( $\omega_2$ ) mode of the ground state shows the strongest IR intensity, followed by the SiO stretching and CSi stretching modes. However, the ground-state bending frequency is so low ( $\omega_2 \sim 60 \text{ cm}^{-1}$ ) that experimental detection might prove difficult. The Si–O stretch has substantial IR intensity, and this fundamental should be observable near  $1200 \text{ cm}^{-1}$ . For the first excited triplet state, the SiO stretching mode presents the largest intensity. The CSi stretching mode of the  $\tilde{A}^3\Pi$  state has a remarkably small intensity.

**E. Renner–Teller Effects.** In Table 4, the Renner parameter ( $\epsilon$ ) and harmonic bending frequency ( $\omega_2$ ) for the  $\tilde{A}^3\Pi$  state of CSiO are presented. These values were determined utilizing the

**TABLE 6: Bond Dissociation (C–SiO) Energies ( $D_e$ ) for the  $\tilde{X}^3\Sigma^-$  State of CSiO**

| level of theory      | in $\text{kcal mol}^{-1}$ | in eV         |
|----------------------|---------------------------|---------------|
| TZ2P SCF             | 6.09 (4.66)               | 0.264 (0.202) |
| TZ2P+diff SCF        | 6.08 (4.65)               | 0.264 (0.202) |
| TZ3P SCF             | 6.33 (4.89)               | 0.274 (0.212) |
| TZ2P(f) SCF          | 6.96 (5.54)               | 0.302 (0.240) |
| TZ2P(f)+diff SCF     | 6.79 (5.38)               | 0.294 (0.233) |
| TZ3P(2f) SCF         | 7.63 (6.17)               | 0.331 (0.268) |
| TZ2P CCSD            | 21.27 (20.18)             | 0.922 (0.875) |
| TZ2P+diff CCSD       | 21.15 (20.12)             | 0.917 (0.872) |
| TZ3P CCSD            | 22.06 (20.95)             | 0.957 (0.908) |
| TZ2P(f) CCSD         | 25.66 (24.54)             | 1.113 (1.064) |
| TZ2P(f)+diff CCSD    | 25.47 (24.41)             | 1.104 (1.059) |
| TZ3P(2f) CCSD        | 27.36 (26.14)             | 1.186 (1.134) |
| cc-pVTZ CCSD         | 26.35 (25.13)             | 1.143 (1.090) |
| cc-pVQZ CCSD         | 28.09 (26.85)             | 1.218 (1.164) |
| TZ2P CCSD(T)         | 25.34 (24.44)             | 1.099 (1.060) |
| TZ2P+diff CCSD(T)    | 25.19 (24.28)             | 1.092 (1.053) |
| TZ3P CCSD(T)         | 26.14 (25.21)             | 1.134 (1.093) |
| TZ2P(f) CCSD(T)      | 29.95 (28.78)             | 1.299 (1.248) |
| TZ2P(f)+diff CCSD(T) | 29.74 (28.44)             | 1.290 (1.233) |
| TZ3P(2f) CCSD(T)     | 31.72 (30.39)             | 1.376 (1.318) |
| cc-pVTZ CCSD(T)      | 30.64 (29.51)             | 1.329 (1.280) |
| cc-pVQZ CCSD(T)      | 32.58 (31.44)             | 1.413 (1.363) |

<sup>a</sup>  $D_0$  values are in parentheses.

equations presented in section III, neglecting anharmonicity. The out-of-plane bending motion is assigned to the upper state ( $\omega_2^+$ ), as the open-shell  $\pi$  MO is kept symmetric during the bending vibration (in the  $^3A'$  state). On the other hand, the in-plane bending motion is assigned to the lower state ( $\omega_2^-$ ), because the open-shell  $\pi$  MO is kept antisymmetric during the bending vibration (in the  $^3A''$  state). The sign of the Renner parameter for the  $\tilde{A}^3\Pi$  state of CSiO is minus ( $-$ ), as was the case for the corresponding states of CCO and SiCO. At the TZ3P(2f) EOM-CCSD level of theory, the theoretically predicted  $\epsilon$  and  $\omega_2$  values for the  $\tilde{A}^3\Pi$  state of CSiO are  $\epsilon = -0.253$  and  $\omega_2 = 337 \text{ cm}^{-1}$ . With the same method, the corresponding  $\epsilon$  and  $\omega_2$  values for the  $\tilde{A}^3\Pi$  state of CCO<sup>15</sup> are  $\epsilon = -0.153$  and  $\omega_2 = 627 \text{ cm}^{-1}$ , compared to the experimental values of  $\epsilon = -0.172$  and  $\omega_2 = 607.8 \text{ cm}^{-1}$ .<sup>5</sup> The predicted values for the  $\tilde{A}^3\Pi$  state of SiCO<sup>17</sup> are  $\epsilon = -0.103$  and  $\omega_2 = 447 \text{ cm}^{-1}$ . Experimental values are not available for SiCO. Among the  $\tilde{A}^3\Pi$  states of the three ketenylidene type molecules, the CSiO radical presents the largest Renner parameter, whereas the SiCO radical has the smallest  $\epsilon$  value.

**F. Energetics.** Table 5 contains the excitation energies for the  $\tilde{A}^3\Pi$  state relative to the  $\tilde{X}^3\Sigma^-$  state at all levels of theory employed in the present study. With the TZ3P(2f) basis set, the excitation energies for the  $\tilde{A}^3\Pi$  state of CSiO were predicted to be 23.4 (SCF), 27.0 (CISD), 28.3 (EOM-CCD), 28.2 (CCSD), and 29.7 kcal/mol [CCSD(T)]. Improved treatment of correlation effects generally increases this energy separation, whereas the increase of the basis set size decreases the energy difference. It should be noted that the EOM-CCSD technique presents an energy separation similar to that from the CCSD method with a given basis set. It is clearly seen that the  $\tilde{X}-\tilde{A}$  splitting is converging to the most reliable value in terms of the correlation level and basis set expansion. At the highest level of theory, cc-pVQZ CCSD(T), the classical  $\tilde{X}-\tilde{A}$  splitting ( $T_e$  value) was predicted to be 29.8 kcal/mol (1.29 eV,  $10\,400 \text{ cm}^{-1}$ ), which is smaller than the corresponding value of 33.1 kcal/mol for the isovalent CCO radical<sup>15</sup> and less than one-half the value of 68.5 kcal/mol for the isoelectronic SiCO radical.<sup>17</sup> Utilizing the three cc-pVQZ CCSD(T) harmonic vibrational frequencies for the  $\tilde{X}^3\Sigma^-$  state and the two cc-pVQZ CCSD(T) harmonic stretching

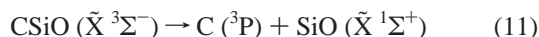
**TABLE 7: Comparison of the Ketenylidene XYO (X, Y = C, Si) Type Radicals**

| physical properties                          | CCO <sup>a</sup> | SiCO <sup>b</sup> | CSiO <sup>c</sup> |
|--|------------------|-------------------|-------------------|
| Renner–Teller type <sup>d</sup>              |                  |                   |                   |
| $\tilde{A}^3\Pi$                             | A                | A                 | A                 |
| XY distance <sup>e</sup>                     |                  |                   |                   |
| $\tilde{X}^3\Sigma^-$                        | 1.370            | 1.825             | 1.854             |
| $\tilde{A}^3\Pi$                             | 1.274            | 1.706             | 1.662             |
|  | (−7.0%)          | (−6.5%)           | (−10.4%)          |
| YO distance <sup>e</sup>                     |                  |                   |                   |
| $\tilde{X}^3\Sigma^-$                        | 1.163            | 1.159             | 1.520             |
| $\tilde{A}^3\Pi$                             | 1.186            | 1.176             | 1.525             |
|  | (+2.0%)          | (+1.5%)           | (+0.3%)           |
| XO distance <sup>e</sup>                     |                  |                   |                   |
| $\tilde{X}^3\Sigma^-$                        | 2.533            | 2.984             | 3.373             |
| $\tilde{A}^3\Pi$                             | 2.460            | 2.882             | 3.187             |
|  | (−2.9%)          | (−3.4%)           | (−5.5%)           |
| dipole moment <sup>f</sup>                   |                  |                   |                   |
| $\tilde{X}^3\Sigma^-$                        | 1.42             | 0.29              | 0.67              |
| $\tilde{A}^3\Pi$                             | 1.47             | 2.49              | 1.77              |
| $\tilde{X}-\tilde{A}$ splitting <sup>g</sup> | 33.1             | 68.5              | 29.8              |

<sup>a</sup> From ref 15. <sup>b</sup> From ref 17. <sup>c</sup> From this study. <sup>d</sup> See text and ref 24. <sup>e</sup> Bond distances are in Å with the TZ3P(2f) CCSD(T) method. <sup>f</sup> Dipole moments are in debye with the TZ3P(2f) CISD method. <sup>g</sup> Splittings ( $T_e$  values) are in kcal mol<sup>−1</sup> with the cc-pVQZ CCSD(T) method.

frequencies with double the TZ3P(2f) EOM-CCSD  $\omega_2$  frequency for the  $\tilde{A}^3\Pi$  state, the zero-point vibrational energy (ZPVE) correction between the two states becomes 458 cm<sup>−1</sup>. Consequently, the quantum mechanical splitting ( $T_0$  value) is determined to be 10 900 cm<sup>−1</sup> (31.1 kcal/mol, 1.35 eV).

**G. Bond Energy for C–SiO.** The bond energy for C–SiO was evaluated from the dissociation reaction



In Table 6, the bond energies for C–SiO at the SCF, CCSD, and CCSD(T) levels of theory are presented. It should be noted that these three methods are size-consistent. The bond energy, dissociation energy for eq 11, is observed to be quite sensitive to correlation effects and basis set size. It is seen that the dissociation energies from the SCF method are not reliable at all. With the most reliable method, cc-pVQZ CCSD(T), the bond energy for C–SiO is predicted to be  $D_e = 32.6$  kcal/mol (1.41 eV), or  $D_0 = 31.4$  kcal/mol (1.36 eV), indicating that the ground state of CSiO is considerably stable, thermodynamically, against the dissociation reaction.

**H. Relative Stability of CSiO and SiCO.** With the TZ3P(2f) CCSD(T) method, the total energies of the ground states of SiCO and CSiO are  $-402.142\,373$  ( $\tilde{X}^3\Sigma^-$  SiCO)<sup>17</sup> and  $-402.035\,826$  hartrees ( $\tilde{X}^3\Sigma^-$  CSiO) (this study). Consequently, the  $\tilde{X}^3\Sigma^-$  state of CSiO lies 66.9 kcal/mol above the  $\tilde{X}^3\Sigma^-$  state of SiCO. With the zero-point vibrational energy correction, this energy separation becomes 65.4 kcal/mol.

**I. Comparisons Among CCO, SiCO, and CSiO.** In Table 7, the structural characteristics and energetics are compared for the ketenylidene (CCO) and monosilaketenyldiene (SiCO and CSiO) radicals. The first excited triplet states ( $\tilde{A}^3\Pi$ ) of these three radicals are classified as type A Renner–Teller molecules. The XY (X, Y = C, Si) bonds of the three molecules are contracted during the  $\tilde{A} \leftarrow \tilde{X}$  excitation, whereas the YO (Y = C, Si) bonds are elongated. The percentage shortening of the molecular size (XO distance) for the  $\tilde{A}^3\Pi$  state relative to the ground state is in the order



The magnitudes of the dipole moments for the ground state of the three species are in the order



whereas those for the first excited triplet states are in the order



It is seen that CCO is the most polar for the ground state, whereas SiCO is the most polar for the first excited triplet state. The  $\tilde{X}-\tilde{A}$  splitting is the largest for the SiCO radical followed by those for the CCO and CSiO radicals.

## VI. Concluding Remarks

The two lowest-lying triplet states of the 2-silaketenyldiene radical have been investigated employing ab initio electronic structure theory. The  $\tilde{X}^3\Sigma^-$  and  $\tilde{A}^3\Pi$  states of CSiO are found to be linear, as was the case for the isovalent CCO and isoelectronic SiCO radicals. The  $\tilde{A}^3\Pi$  state of CSiO is classified as a type A Renner–Teller molecule, and its Renner parameter and harmonic bending frequency are determined to be  $\epsilon = -0.253$  and  $\omega_2 = 337$  cm<sup>−1</sup>. With our most reliable level of theory, cc-pVQZ CCSD(T), the classical  $\tilde{X}-\tilde{A}$  splitting of CSiO has been predicted to be 29.8 kcal/mol (1.29 eV, 10 400 cm<sup>−1</sup>), and the quantum mechanical energy separation to be 31.1 kcal/mol (1.35 eV, 10 900 cm<sup>−1</sup>). With the same method, the bond energy for the ground state of the CSiO radical was determined to be  $D_e = 32.6$  ( $D_0 = 31.4$ ) kcal/mol, which indicates that CSiO is thermodynamically stable in its ground state.

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